SWITCHMODE™ Power Rectifier 100 V, 10 A

Features and Benefits

- Low Forward Voltage: 0.61 V @ 125°C
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 10 A Total (5.0 A Per Diode Leg)
- Guard-Ring for Stress Protection
- Pb–Free Package is Available

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 Units Per Plastic Tube

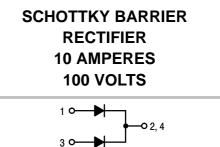
MAXIMUM RATINGS

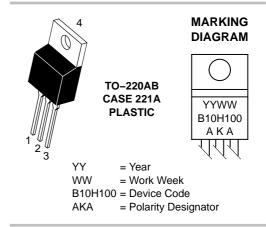
Please See the Table on the Following Page



ON Semiconductor®

http://onsemi.com





ORDERING INFORMATION

Device	Package	Shipping
MBR10H100CT	TO-220	50 Units/Rail
MBR10H100CTG	TO-220 (Pb-Free)	50 Units/Rail

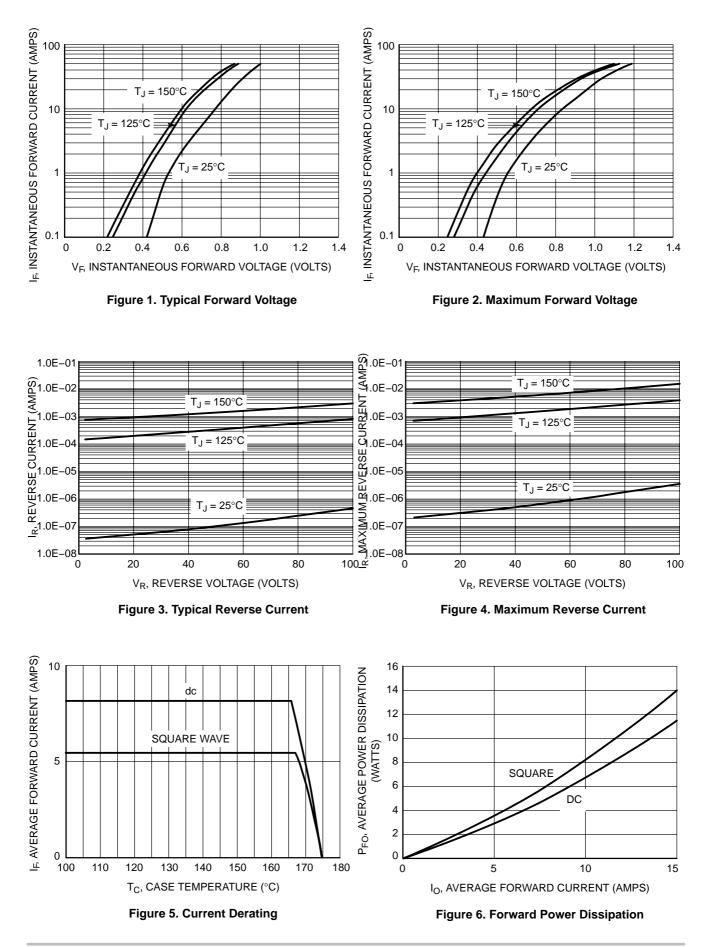
MAXIMUM RATINGS (Per Diode Leg)

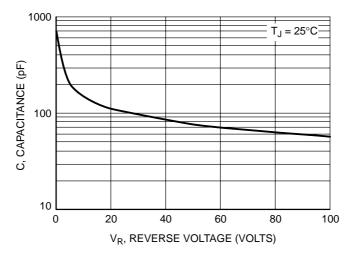
Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	V	
Average Rectified Forward Current (Rated V_R) T _C = 168°C	I _{F(AV)}	5.0	A	
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz) T_C = 165°C	I _{FRM}	10	А	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	180	А	
Operating Junction Temperature (Note 1)	TJ	+175	°C	
Storage Temperature	T _{stg}	-65 to +175	°C	
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs	
Controlled Avalanche Energy (see test conditions in Figures 10 and 11)	W _{AVAL}	100	mJ	
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V	
THERMAL CHARACTERISTICS				
Maximum Thermal Resistance – Junction–to–Case – Junction–to–Ambient	R _{θJC} R _{θJA}	2.0 60	°C/W	
ELECTRICAL CHARACTERISTICS (Per Diode Leg)				
Maximum Instantaneous Forward Voltage (Note 2)	v _F		V	

Maximum Instantaneous Forward Voltage (Note 2)	٧ _F		V
$(I_F = 5.0 \text{ A}, T_C = 25^{\circ}\text{C})$		0.73	
$(I_F = 5.0 \text{ A}, T_C = 125^{\circ}\text{C})$		0.61	
$(I_{\rm F} = 10 \text{ A}, T_{\rm C} = 25^{\circ}\text{C})$		0.85	
$(I_F = 10 \text{ A}, T_C = 125^{\circ}\text{C})$		0.71	
Maximum Instantaneous Reverse Current (Note 2)	i _R		mA
(Rated DC Voltage, $T_C = 125^{\circ}C$)		4.5	
(Rated DC Voltage, $T_C = 25^{\circ}C$)		0.0035	

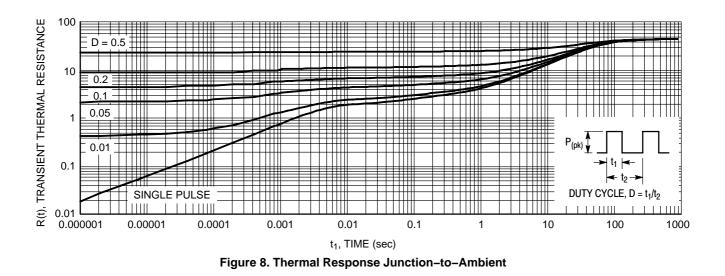
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected. 1. The heat generated must be less than the thermal conductivity from Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.









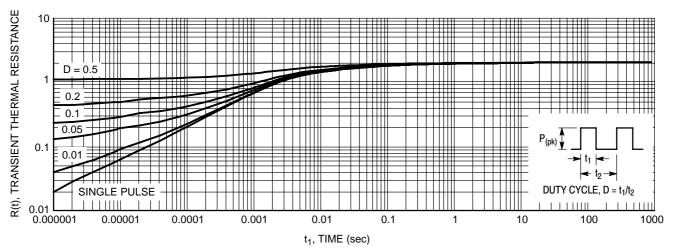


Figure 9. Thermal Response Junction-to-Case

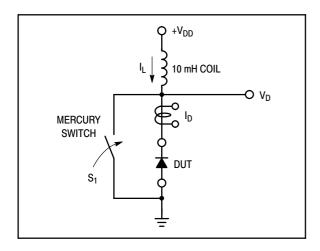


Figure 10. Test Circuit

The unclamped inductive switching circuit shown in Figure 10 was used to demonstrate the controlled avalanche capability of this device. A mercury switch was used instead of an electronic switch to simulate a noisy environment when the switch was being opened.

When S_1 is closed at t_0 the current in the inductor I_L ramps up linearly; and energy is stored in the coil. At t_1 the switch is opened and the voltage across the diode under test begins to rise rapidly, due to di/dt effects, when this induced voltage reaches the breakdown voltage of the diode, it is clamped at BV_{DUT} and the diode begins to conduct the full load current which now starts to decay linearly through the diode, and goes to zero at t_2 .

By solving the loop equation at the point in time when S_1 is opened; and calculating the energy that is transferred to the diode it can be shown that the total energy transferred is equal to the energy stored in the inductor plus a finite amount of energy from the V_{DD} power supply while the diode is in breakdown (from t_1 to t_2) minus any losses due to finite component resistances. Assuming the component resistive

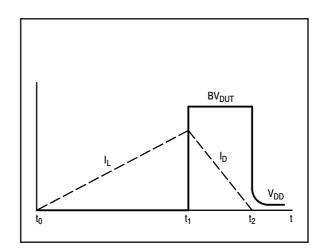


Figure 11. Current–Voltage Waveforms

elements are small Equation (1) approximates the total energy transferred to the diode. It can be seen from this equation that if the V_{DD} voltage is low compared to the breakdown voltage of the device, the amount of energy contributed by the supply during breakdown is small and the total energy can be assumed to be nearly equal to the energy stored in the coil during the time when S₁ was closed, Equation (2).

EQUATION (1):

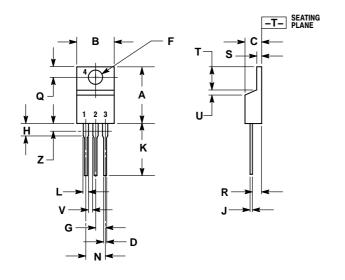
$$W_{AVAL} \approx \frac{1}{2} LI_{LPK}^{2} \left(\frac{BV_{DUT}}{BV_{DUT} - V_{DD}} \right)$$

EQUATION (2):

$$W_{AVAL} \approx \frac{1}{2} LI_{LPK}^2$$

PACKAGE DIMENSIONS

TO-220 PLASTIC CASE 221A-09 **ISSUE AA**



NOTES

DIMENSIONING AND TOLERANCING PER ANSI 1. Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE 3 ALLOWED.

	INCHES		MILLIN	NETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
۷	0.045		1.15	
Ζ		0.080		2.04

SWITCHMODE is a trademark of Semiconductor Components Industries, LLC.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC products are not designed, intended, or authorized for use a components in systems intended for surgical implant into the body, or other applications and actual performance may any content applications. Intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative